

High-speed Switching Transistor(−60V / −5A)

2SA1952 / 2SA1906 / 2SA1757

Features

- 1) High switching speed, typically $t_f=0.15\ \mu s$ at $I_c=-3A$.
- 2) Low saturation voltage, typically $V_{CE(sat)}=-0.2V$ at $I_c/I_b=-3A/-0.15A$.
- 3) Wide SOA. (safe operating area)
- 4) Complements the 2SC5103 / 2SC4596.

Packaging specifications and h_{FE}

Type	2SA1952	2SA1906	2SA1757
Package	CPT3	PSD3	TO-220FP
h_{FE}	Q	DEF	F
Code	TL	TL	—
Basic ordering unit (pieces)	3000	1000	500

Electrical characteristics ($T_a=25^\circ C$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	-100	—	—	V	$I_c=-50\ \mu A$
Collector-emitter voltage	$BV_{CEO(SUS)}$	-60	—	—	V	$I_c/I_b=-3A/-0.3A, L=1mH$
Collector-emitter breakdown voltage	BV_{CEO}	-60	—	—	V	$I_c=-1mA$
Emitter-base breakdown voltage	BV_{EBO}	-5	—	—	V	$I_e=50\ \mu A$
Collector cutoff current	I_{CBO}	—	—	-10	μA	$V_{ce}=-100V$
Emitter cutoff current	I_{EBO}	—	—	-10	μA	$V_{eb}=-5V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	-0.3	V	$I_c/I_b=-3A/-0.15A$
		—	—	-0.5	V	$I_c/I_b=-4A/-0.2A$
Base-emitter saturation voltage	$V_{BE(sat)}$	—	—	-1.5	V	$I_c/I_b=-3A/-0.15A$
		—	—	-1.2	V	$I_c/I_b=-4A/-0.2A$
DC current transfer ratio	2SA1952 2SA1906 2SA1757	120 60 160	—	270 320 320	—	$V_{ce}=-2V, I_c=-1A$
Transition frequency	f_T	—	80	—	MHz	$V_{ce}=-10V, I_e=0.5A, f=30MHz$
Output capacitance	Cob	—	130	—	pF	$V_{ce}=-10V, I_e=0A, f=1MHz$
Turn-on time	t_{on}	—	—	0.3	μs	$I_c=-3A, R_L=10\Omega$
Storage time	t_{stg}	—	—	1.5	μs	$I_{b1}=-I_{z2}=-0.15A$
Fall time	t_f	—	—	0.3	μs	$V_{cc}\sim-30V$

Absolute maximum ratings ($T_a=25^\circ C$)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	-100	V
Collector-emitter voltage	V_{CEO}	-60	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_c	-5	A
		-10	A (Pulse)
Collector power dissipation	2SA1757 2SA1952 2SA1757, 2SA1906	1 10 1.5 2.5 2 25	W ($T_c=25^\circ C$)
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55~+150	°C

(96-603-A314)

High-speed Switching Transistor(60V / 5A)

2SC5103 / 2SC4596

Features

- 1) Low saturation voltage, typically $V_{CE(sat)}=0.15V$ at $I_c/I_b=3A/0.15A$.
- 2) High switching speed, typically $t_f=0.1\ \mu s$ at $I_c=3A$.
- 3) Wide SOA. (safe operating area)
- 4) Complements the 2SA1952 / 2SA1757.

Packaging specifications and h_{FE}

Type	2SC5103	2SC4596
Package	CPT3	TO-220FP
h_{FE}	PQ	EF
Code	TL	—
Basic ordering unit (pieces)	2500	500

Electrical characteristics ($T_a=25^\circ C$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	100	—	—	V	$I_c=50\ \mu A$
Collector-emitter voltage	$BV_{CEO(SUS)}$	60	—	—	V	$I_c/I_b=3A/0.3A, L=1mH$
Collector-emitter breakdown voltage	BV_{CEO}	60	—	—	V	$I_c=1mA$
Emitter-base breakdown voltage	BV_{EBO}	5	—	—	V	$I_e=50\ \mu A$
Collector cutoff current	I_{CBO}	—	—	10	μA	$V_{ce}=100V$
Emitter cutoff current	I_{EBO}	—	—	10	μA	$V_{eb}=5V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	0.15	0.3	V	$I_c/I_b=3A/0.15A$
		—	—	0.5	V	$I_c/I_b=4A/0.2A$
		—	—	1.2	V	$I_c/I_b=3A/0.15A$
Base-emitter saturation voltage	$V_{BE(sat)}$	—	—	1.5	V	$I_c/I_b=4A/0.2A$
DC current transfer ratio	2SC5103 2SC4596	82 100	—	270 320	—	$V_{ce}/I_c=2V/1A$
Transition frequency	f_T	—	120	—	MHz	$V_{ce}=10V, I_e=0.5A, f=30MHz$
Output capacitance	Cob	—	80	—	pF	$V_{ce}=10V, I_e=0A, f=1MHz$
Turn-on time	t_{on}	—	—	0.3	μs	$I_c=3A, R_L=10\Omega$
Storage time	t_{stg}	—	—	1.5	μs	$I_{b1}=-I_{z2}=-0.15A$
Fall time	t_f	—	—	0.1	μs	$V_{cc}\sim30V$

* Single pulse $P_w=100ms$

* Measured using pulse current.

(96-199-C314)